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QPA4563A

DC to 3500MHz, CASCADABLE SiGe HBT MMIC AMPLIFIER

The QPA4563A is a high performance SiGe HBT MMIC amplifier. A Darlington configuration provides high F_T and excellent thermal performance. The heterojunction increases breakdown voltage and minimizes leakage current between junctions. Cancellation of emitter junction non-linearities results in higher suppression of intermodulation products. Only two DC-blocking capacitors, a bias resistor, and an optional RF choke are required for operation.



SOT-363 Package

Features

- DC to 3500MHz Operation
- Cascadable 50Ω

Applications

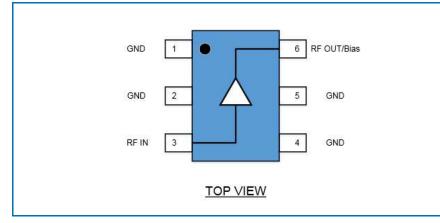
- High Gain: 20.4 dB Typical at 1950 MHz
- Operates From Single DC Supply
- Low Thermal Resistance Package

Power Amplifier Driver Amplifier

Cellular, PCS, GSM, UMTS

IF/RF Buffer Amplifier

Wireless Data, Satellite



Functional Block Diagram

Ordering Information

QPA4563ASQ	Sample Bag with 25 pieces
QPA4563ASR	7" Reel with 100 pieces
QPA4563ATR7	7" Reel with 3000 pieces
QPA4563APCK401	850MHz, +8V Operation PCBA with 5-piece Sample Bag

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QPA4563A

Absolute Maximum Ratings

Parameter	Rating	Units
Device Voltage(V _D)	+5.0	V
Device Current (ID)	90	mA
RF Input Power Note 1	+18	dBm
Storage Temperature	-55 to +150	°C
ESD Rating (HBM)	TBD	-
Moisture Sensitivity Level	MSL1	-

Notes:

1. Load Condition 1: $Z_L = 50 \Omega$

- Operation of this device beyond any one of these limits may cause permanent damage. For reliable continuous operation, the device voltage and current must not exceed the maximum operating values specified in this table.
- 3. Bias Conditions should also satisfy the following expression: $I_DV_D <\!(T_J T_L)/R_{TH},$ and $T_L =\!T_{LEAD}.$

Recommended Operating Conditions

Parameter		Units		
Falameter	Min	Тур	Max	Units
Operating Temperature Range	-40		+105	°C
Junction Temperature (TJ)			+125	°C
Device Operating Voltage		+3.6		V

Electrical Specifications – General

Parameter	S	Specification		Units	Conditions	
Parameter	Min	Тур	Max	Units	Conditions	
		23.5		dB	850MHz	
Small Signal Gain, S21		20.4		dB	1950MHz	
		19.2		dB	2400MHz	
		+16.0		dBm	850MHz	
Output Power at 1 dB Compression		+16.2		dBm	1950MHz	
		+15.8		dBm	2400MHz	
		+30.0		dBm	850MHz	
Output Third Order Intercept Point		+29.4		dBm	1950MHz	
		+28.9		dBm	2400MHz	
		28.7		dB	850MHz	
Input Return Loss, S11		17.1		dB	1950MHz	
		16.9		dB	2400MHz	
		25.0		dB	850MHz	
Output Return Loss, S22		14.9		dB	1950MHz	
		14.2		dB	2400MHz	
•	V _D = +3.6 V, _{BIAS} = 100Ω,				P3 Tone Spacing=1 MHz, P_{OUT} per tone = -10 dBm,	

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RFMD + TriQuint = Qorvo



Caution! ESD sensitive device.



RFMD Green: RoHS status based on EU Directive 2011/65/EU (at time of this document revision), halogen free per IEC 61249-2-21, < 1000 ppm each of antimony trioxide in polymeric materials and red phosphorus as a flame retardant, and <2% antimony in solder.

Exceeding any one or a combination of the Absolute Maximum Rating conditions may cause permanent damage to the device. Extended application of Absolute Maximum Rating conditions to the device may reduce device reliability. Specified typical performance or functional - operation of the device under Absolute Maximum Rating conditions is not implied.



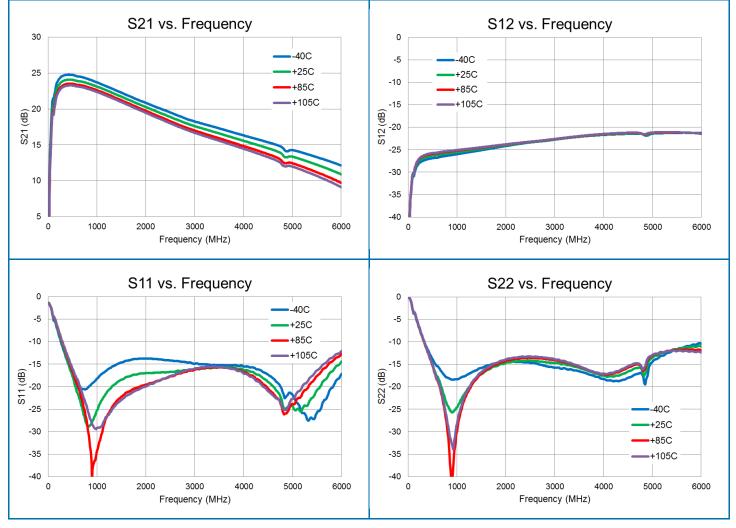


QPA4563A

Electrical Specifications – General (Continued)

Parameter	Specification			Units	Conditions
	Min	Тур	Max	Units	Conditions
		25.8		dB	850MHz
Reverse Isolation, S12		24.1		dB	1950MHz
		23.5		dB	2400MHz
		2.3		dB	850MHz
Noise Figure		2.5		dB	1950MHz
		2.8		dB	2400MHz
Thermal Resistance		118		°C/W	
Device Operating Current		45		mA	
Test Conditions unless otherwise specified: $+V_D = +3.6 \text{ V}, V_S = +8 \text{ V}, I_D = 45 \text{ mA Typ.}, \text{ OIP3 Tone Spacing=1 MHz}, P_{\text{OUT}} \text{ per tone} = -10 \text{ dBm}, R_{\text{BIAS}} = 100\Omega, T_L = +25^{\circ}\text{C}, Z_S = Z_L = 50 \Omega$					

Typical Performance Using 850MHz Application Circuit

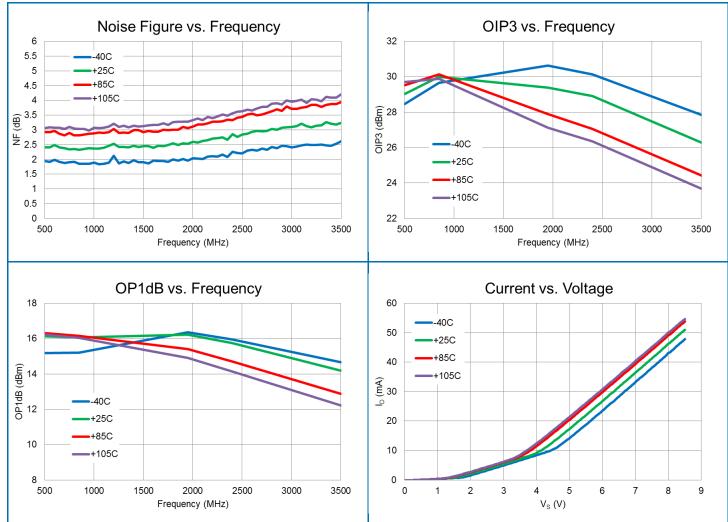


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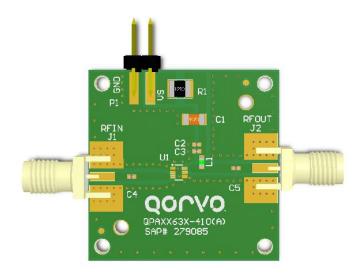
Typical Performance Using 850MHz Application Circuit

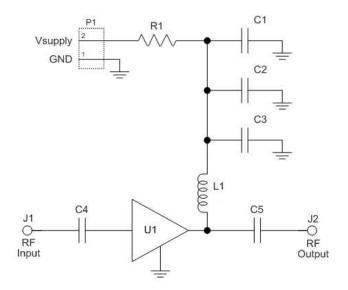




QPA4563A

Evaluation Board and Schematic





Evaluation Board Bill of Materials For 850MHz Application Circuit

Description	Reference Designator	Manufacturer	Manufacturer's P/N
Gain Block	U1	QORVO	QPA4563A
РСВ	NA	Viasystems Technologies Corp	QPAXX63X-410(A)
CAP, 1uF, 10%, 25V, X7R, 1206	C1	Murata Electronics	GRM31MR71E105KA01L
CAP, 1000pF, 10%, 50V, X7R, 0402	C2	Murata Electronics	GRM155R71H102KA01D
CAP, 68pF, 5%, 50V, C0G, 0402	C3	Murata Electronics	GRM1555C1H680JA01D
CAP, 100pF, 5%, 50V, C0G, 0402	C4, C5	Murata Electronics	GRM1555C1H101JA01D
RES, 100 OHM, 5%, 1/2W, 1210	R1	Panasonic Industrial Devices	ERJ-14YJ101U
IND, 33nH, 5%, M/L, 0603	L1	Murata Electronics	LL1608-FSL33NJ
CONN, SMA, EL, FLT, 0.068" SPE-000318	J1. J2	Amphenol RF Asia Corp	901-10426
CONN, HDR, ST, 1x2, 0.100", HI-TEMP, T/H	P1	Samtec Inc.	HTSW-102-07-G-S

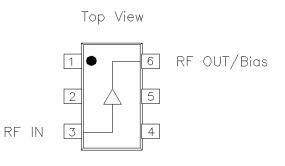


QPA4563A

Component Values For Specific Frequency and Voltage in Application Circuit

Reference	Frequency (MHz)							
Designator	500	850	1950	2400	3500			
C_4, C_5	220pF	100pF	68pF	56pF	39pF			
C ₃	100pF	68pF	22pF	22pF	15pF			
L1	68nH	33nH	22nH	18nH	15nH			
Required Bias Resistance for I _D = 45mA Bias Resistance = R _{BIAS} + R _{LDC} = (V _S -V _D) / I _D								
Supply Vol	tage (Vs)	+6 V	+8 V	+10 V	+12 V			
Bias Resistanc	ce (R _{1 =} R _{Bias})	51 Ω	100 Ω	150 Ω	180 Ω			
Note: Bias resistor improves current stability over temperature								

Pin Configuration and Description



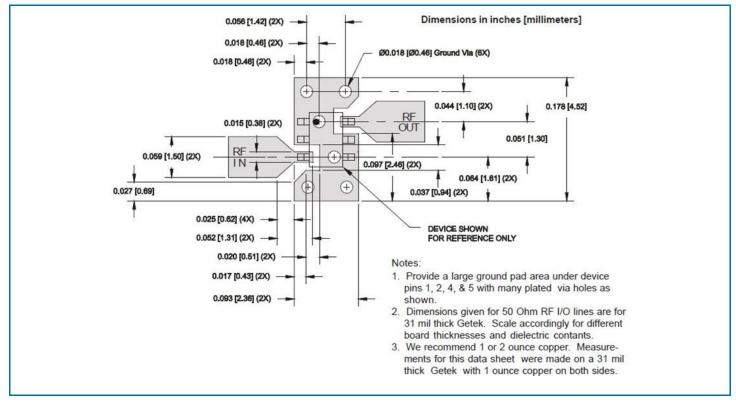
Pin	Label	Description
3	RF IN	RF Input pin. This pin requires the use of an external DC blocking capacitor as shown in the application schematic.
1, 2, 4, 5	GND	Connect to ground per application circuit drawing. For best performance, vias should be used as shown in the recommended pad layout.
6	RF OUT/BIAS	RF Output and Bias pin. Bias will be supplied to this pin through an external RF choke. A DC blocking capacitor is necessary on the RF output as shown in the application circuit.



QPA4563A

Package Marking

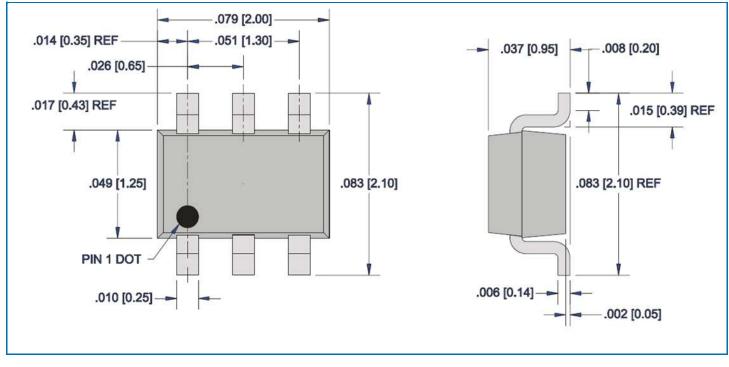
Suggested Pad Layout (Dimensions in inches [millimeters])





QPA4563A

Package Outline (Dimensions in inches [millimeters])



Contact Information

For the latest specifications, additional product information, worldwide sales and distribution locations:

Web: www.rfmd.com Tel: 1-844-890-8163 Email: customer.support@gorvo.com

For information about the merger of RFMD and TriQuint as Qorvo:

Web: www.qorvo.com

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